## NSN 5962-01-088-1629

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-088-1629

Body Length:
0.840 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
715.0 milliwatts
Operating Tempurature Range: -55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set, type no. An/fps-115
Features Provided:
Hermetically sealed and monolithic and positive outputs and 3-state output and bipolar and programmable and programmed and w/disable
and w/enable and w/storage and w/decoded output and w/buffered output and schottky
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
D-2 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
49956-952369 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:

16 printed circuit

Shelf Life:

NI/o

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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